TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LVX14F, TC74LVX14FN, TC74LVX14FT

HEX SCHMITT INVERTER

The TC74LVX14 is a high speed CMOS HEX SCHMITT INVERTER fabricated with silicon gate C²MOS technology. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation. This device is suitable for low voltage and battery operated systems.

Pin configuration and function are the same as the TC74LVX04 but the inputs have hysteresis and with its schmitt trigger function, the TC74LVX14 can be used as a line receivers which will receive slow input signals. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage.

This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

• High speed : $t_{pd} = 6.8$ ns (Typ.) ($V_{CC} = 3.3$ V) • Low power dissipation : $I_{CC} = 2\mu$ A (Max.) ($T_{a} = 25$ °C)

Power down protection is provided on all inputs.

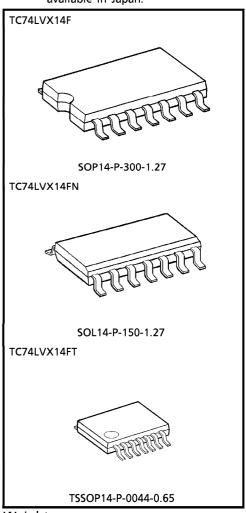
Balanced propagation delays

: t_{pLH}≃t_{pHL}

• Low niose : $V_{OLP} = 0.5V$ (Max.)

Pin and function compatible with 74HC14

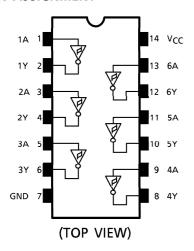
(Note) The JEDEC SOP (FN) is not available in Japan.



Weight

SOP14-P-300-1.27 : 0.18g (Typ.) SOL14-P-150-1.27 : 0.12g (Typ.) TSSOP14-P-0044-0.65 : 0.06g (Typ.)

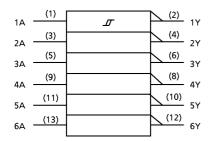
PIN ASSIGNMENT



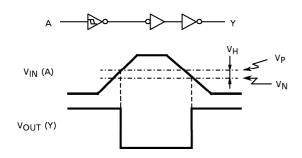
TRUTH TABLE

INPUTS	OUTPUTS
Α	Υ
L	Н
Н	Ĺ

IEC LOGIC SYMBOL



SYSTEM DIAGRAM, WAVEFORM



MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	Vcc	- 0.5~7.0	V
DC Input Voltage	VIN	- 0.5~7.0	٧
DC Output Voltage	Vout	-0.5~V _{CC} +0.5	٧
Input Diode Current	IK	– 20	mA
Output Diode Current	loк	± 20	mA
DC Output Current	IOUT	± 25	mA
DC V _{CC} /Ground Current	lcc	± 50	mA
Power Dissipation	PD	180	mW
Storage Temperature	T _{stg}	-65∼150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2.0~3.6	V
Input Voltage	VIN	0~5.5	٧
Output Voltage	Vout	0~V _{CC}	٧
Operating Temperature	T _{opr}	- 40∼85	°C

ELECTRICAL CHARACTERISTICS

DC characteristics

PARAMETER		SYM-			Vcc	٦	Ta = 25°C		$Ta = -40 \sim 85^{\circ}C$		UNIT
FARAI	WIETER	BOL	TEST CONDITION		(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Threshold	"H" Level	VP				_	_	2.2	_	2.2	V
Voltage	"L" Level	٧N			3.0	0.9	_	_	0.9	_] '
Hysteresis \	/oltage	VΗ			3.0	0.3	_	1.2	0.3	1.2	V
			V _{IN} = V _{IL}	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	_	1.9	_	
Output "	"H" Level	VOL		$I_{OH} = -50\mu A$	3.0	2.9	3.0	_	2.9	_	
				$I_{OH} = -4mA$	3.0	2.58	_	_	2.48	_] _v [
Voltage		V _{OL}		$I_{OL} = 50 \mu A$	2.0		0.0	0.1		0.1]
"L"	"L" Level		V _{IN} = V _{IH}	$I_{OL} = 50 \mu A$	3.0	_	0.0	0.1	_	0.1	
				I _{OL} = 4mA	3.0	_	_	0.36	_	0.44	
Input Leakage Current I _{IN} V _{IN} = 5.5V or GND		3.6	_	_	± 0.1		± 1.0	μΑ			
Quiescent S Current	Supply	ICC	V _{IN} = V _{CC} o	r GND	3.6	_	_	2.0	_	20.0	μΑ

PARAMETER	SYM-	TEST				Га = 25°(C	Ta = -4	.0~85°C	UNIT
PARAIVIETER	BOL	CONDITION	V _C C (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
	+		2.7	15	_	8.7	16.3	1.0	19.5	
Propagation Delay	t _{pLH}		2.7	50	_	11.2	19.8	1.0	23.0	l ne
Time	+		22402	15	_	6.8	10.6	1.0	12.5	ns
	t _{pHL}		3.3 ± 0.3	50	_	9.3	14.1	1.0	16.0	
Output To Output	tosLH	(Note 1)	2.7	50	_	_	1.5	_	1.5	
Skew	tosHL	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
Input Capacitance	CIN	(Note 2)			_	4	10	_	10	рF
Power Dissipation Capacitance	C _{PD}	(Note 3)			_	21	_	_	_	pF

(Note 1) Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

(Note 2) Parameter guaranteed by design.

(Note 3) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

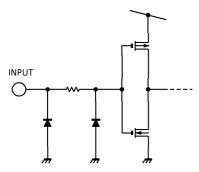
Average operating current can be obtained by the equation :

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6 \text{ (per gate)}$

Noise characteristics (Ta = 25°C, Input $t_r = t_f = 3$ ns, $C_L = 50$ pF)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic VOL	V _{OLP}		3.3	0.3	0.5	٧
Quiet Output Minimum Dynamic VOL	V _{OLV}		3.3	- 0.3	- 0.5	V
Minimum High Level Dynamic Input Voltage	VIHD		3.3	_	2.2	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}		3.3	_	0.9	V

INPUT EQUIVALENT CIRCUIT

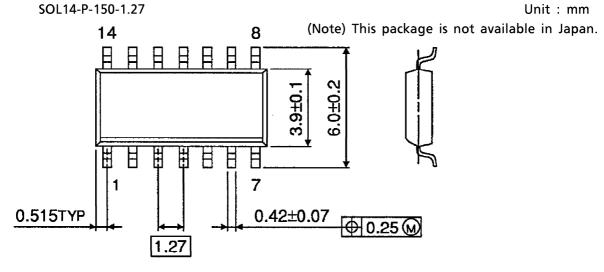


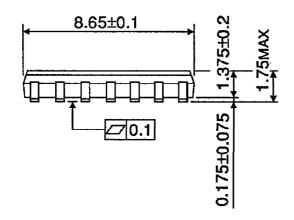
0.8±0.2

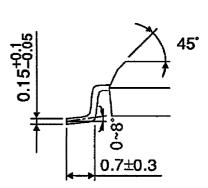
PACKAGE DIMENSIONS SOP14-P-300-1.27 Unit : mm 14 8 2.09.6.98 1.34TYP 10.8MAX 10.3±0.2 2.09.5.0 1.27 10.8MAX

Weight: 0.18g (Typ.)

PACKAGE DIMENSIONS





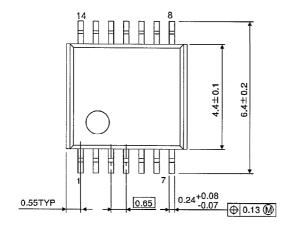


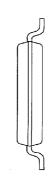
Weight: 0.12g (Typ.)

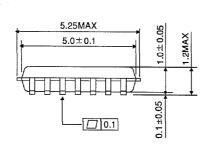
PACKAGE DIMENSIONS

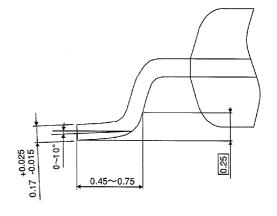
TSSOP14-P-0044-0.65

Unit: mm









Weight: 0.06g (Typ.)

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